

RM35HG-34S

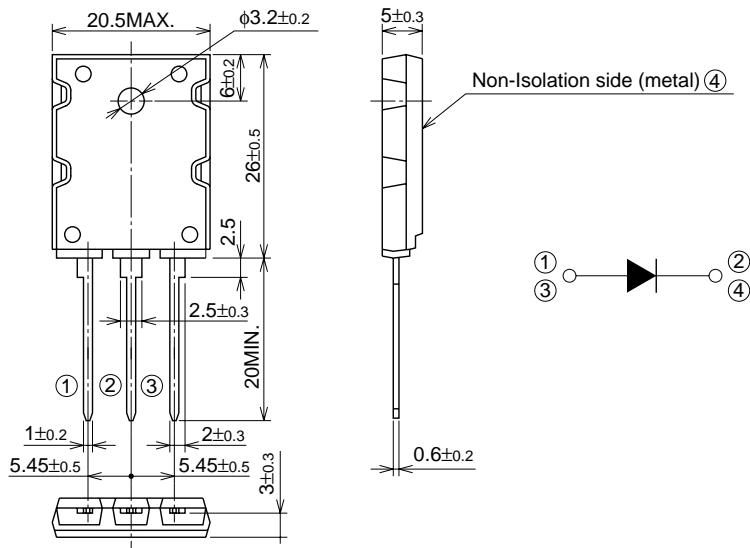
- **IDC** DC current **35A**
- **V_{RMM}** Repetitive peak reverse voltage **1700V**
- **t_{rr}** Reverse recovery time **0.3μs**
- **ONE ARM**
- **Non-Insulated Type**

APPLICATION

For snubber circuit (IPM or IGBT module)

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



MITSUBISHI FAST RECOVERY DIODE MODULES

RM35HG-34S

HIGH SPEED SWITCHING USE
NON-INSULATED TYPE

ABSOLUTE MAXIMUM RATINGS ($T_j=25^\circ\text{C}$)

Symbol	Parameter	Voltage class	Unit
		34	
V_{RRM}	Repetitive peak reverse voltage	1700	V
V_{DRM}	Non-repetitive peak reverse voltage	1700	V
$V_R(\text{DC})$	Reverse DC voltage	1360	V

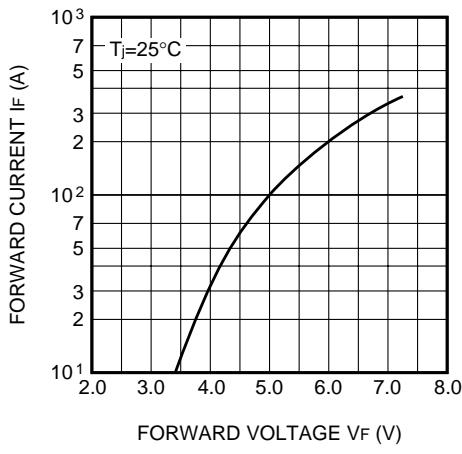
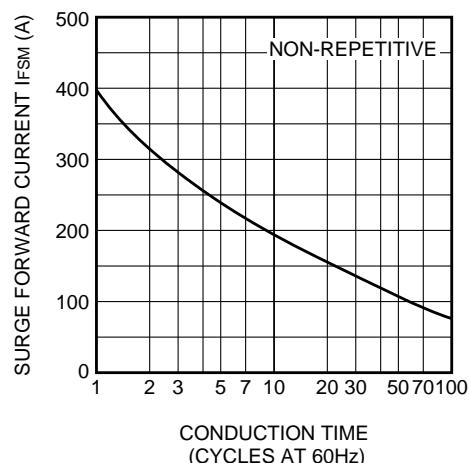
Symbol	Parameter	Conditions	Ratings	Unit
I_{DC}	DC current	Resistive load, $T_c=80^\circ\text{C}$ ①, ③ Collective of terminal	35	A
I_{FSM}	Surge (non-repetitive) forward current	One half cycle at 60Hz, peak value ①, ③ Collective of terminal	400	A
T_j	Junction temperature		-40~+150	$^\circ\text{C}$
T_{stg}	Storage temperature		-40~+125	$^\circ\text{C}$
V_{iso}	Isolation voltage	Charged part to case	—	V
—	Mounting torque	Mounting screw M3	0.59~0.98	N·m
—	Weight	Typical value	10	g

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I_{RRM}	Repetitive reverse current	$T_j=25/125^\circ\text{C}$, V_{RRM} applied	—	—	0.1/1.0	mA
V_{FM}	Forward voltage	$T_j=25^\circ\text{C}$, $I_{FM}=100\text{A}$, Instantaneous meas.	—	—	5.0	V
t_{rr}	Reverse recovery time	$I_{FM}=100\text{A}$, $T_j=25^\circ\text{C}$, $dI/dt=-500\text{A}/\mu\text{s}$, $V_R=600\text{V}$	—	—	0.3	μs
Q_{rr}	Reverse recovery charge		—	—	—	μC
$R_{th(j-c)}$	Thermal resistance	Junction to case	—	—	0.5	$^\circ\text{C}/\text{W}$
$R_{th(c-f)}$	Contact thermal resistance	Case to fin, conductive grease applied	—	—	0.5	$^\circ\text{C}/\text{W}$

Aug.1999



PERFORMANCE CURVES**MAXIMUM FORWARD CHARACTERISTIC****RATED SURGE FORWARD CURRENT****MAXIMUM TRANSIENT THERMAL IMPEDANCE**